



**D10SB10 THRU D10SB100**

**SINGLE PHASE GLASS**

**PASSIVATED SIP BRIDGE RECTIFIER**

**VOLTAGE: 100 TO 1000V CURRENT: 10A**

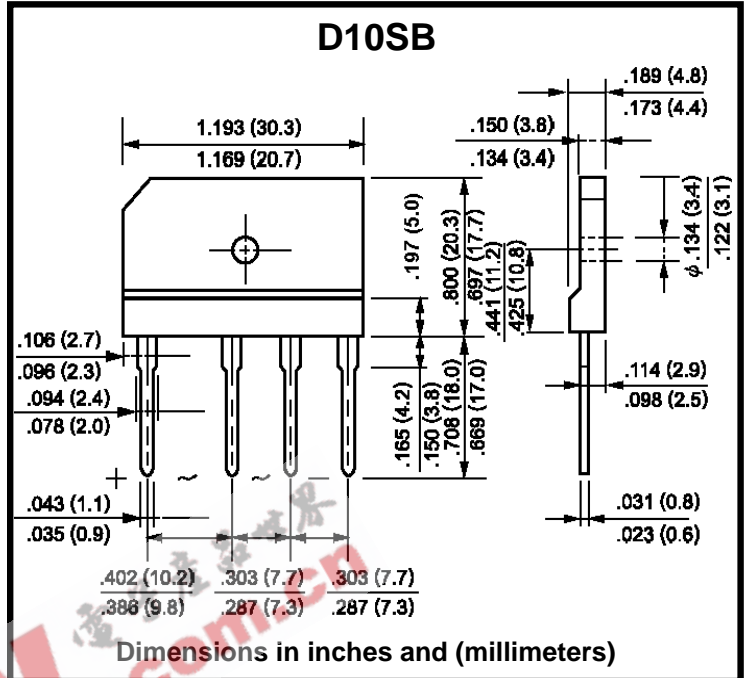
**TECHNICAL SPECIFICATION**

**FEATURES**

- Glass passivated junction chip
- Ideal for printed circuit board
- Reliable low cost construction utilizing molded plastic technique
- Surge overload rating: 200 A peak
- High temperature soldering guaranteed: 250°C/10sec/ 0.375" (9.5mm) lead length at 5 lbs tension

**MECHANICAL DATA**

- Terminal: Plated leads solderable per MIL-STD 202E, method 208C
- Case: UL-94 Class V-O recognized flame retardant epoxy
- Polarity: Polarity symbol marked on body
- Mounting position: Any



**MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS**

(Single-phase, half-wave, 60Hz, resistive or inductive load rating at 25°C, unless otherwise stated, for capacitive load, derate current by 20%)

RATINGS	SYMBOL	D10SB	D10SB	D10SB	D10SB	D10SB	D10SB	UNITS
		10	20	40	60	80	100	
Maximum Repetitive Peak Reverse Voltage	$V_{RRM}$	100	200	400	600	800	1000	V
Maximum RMS Voltage	$V_{RMS}$	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	$V_{DC}$	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current ( $T_a=70^\circ\text{C}$ )	$I_{F(AV)}$	10						A
Peak Forward Surge Current (8.3ms single half sine-wave superimposed on rated load)	$I_{FSM}$	200						A
Maximum Instantaneous Forward Voltage (at forward current 5.0ADC)	$V_F$	1.1						V
Maximum DC Reverse Current (at rated DC blocking voltage)	$I_R$	$T_a=25^\circ\text{C}$						$\mu\text{A}$
		$T_a=125^\circ\text{C}$						$\mu\text{A}$
Storage and Operating Junction Temperature	$T_{STG}, T_J$	-55 to + 150						$^\circ\text{C}$